

## High Sensitivity Micropower Omnipolar Hall-effect Switch

### Features

- High sensitive omnipolar operation.
- Micropower operation.  
Typ 0.8 $\mu$ A (average:  $V_{DD}=1.8V$ ).
- Ultra small package: SOT23-3L.
- On board voltage regulator for 1.6V to 5.5V range.
- Wide operating temperature range: -40 °C to 85°C.
- ESD (HBM) > 6KV.

### Applications

- Smartphone.
- Notebook computer.
- Handheld gaming consoles.
- Bluetooth headset.
- DV.
- Contact-less switch, Level, proximity and position switches in consumer products.

### General Description

AW86504BSTR is a high-sensitivity micropower Omnipolar Hall effect switch IC with internal pull up and pull down capability. AW86504BSTR uses a hibernating clocking system to reduce power consumption, which the total power consumption in normal operation is typically 0.8 $\mu$ A with a 1.8V power source. Mainly designed for portable devices such as laptop computer, smartphone and bluetooth headset etc. The supply range of AW86504BSTR is 1.6V to 5.5V to support portable equipment. To minimize PCB space, the AW86504BSTR has ultra small package: SOT23-3L.

When the magnetic field strength is greater than  $B_{op}$ , then the device output is pulled low; When the magnetic field strength is less than  $B_{rp}$ , then the device output is pulled high; When the magnetic field strength is between  $B_{op}$  and  $B_{rp}$ , then the device output remains in the previous state.

### Typical Application Circuit

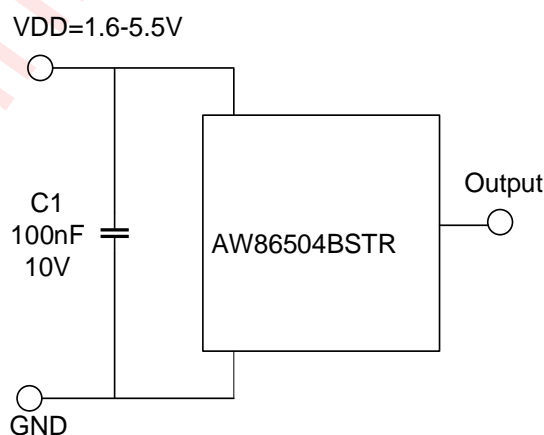


Figure 1 Typical Application Circuit of AW86504BSTR

## Pin Configuration And Top Mark

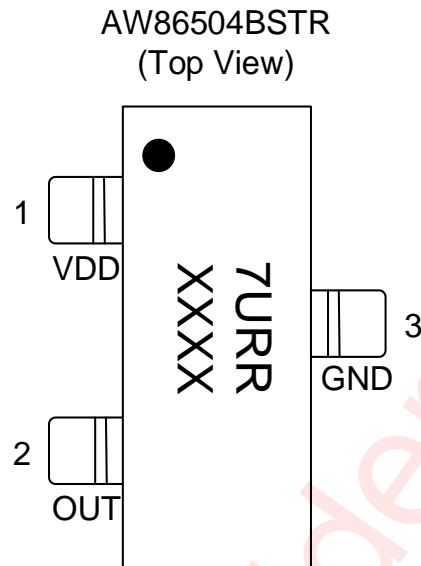


Figure 2 Pin Configuration and Top Mark

## Pin Definition

NO	Name	Description
1	VDD	Power Supply
2	OUT	Output pin
3	GND	Ground

## Functional Block Diagram

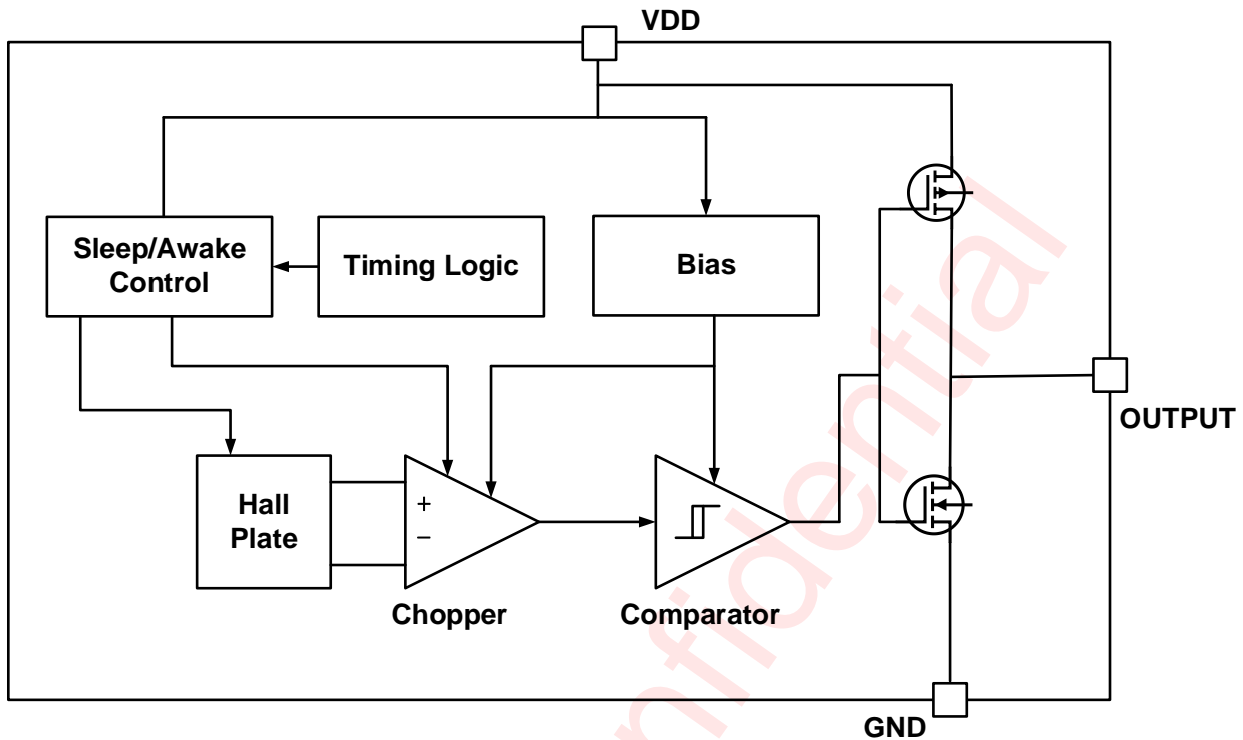


Figure 3 Functional Block Diagram

## Ordering Information

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW86504BSTR	-40°C~85°C	SOT23-3L	7URR	MSL3	ROHS+HF	3000 units/ Tape and Reel

## Detailed Functional Description

When the magnetic field strength is greater than  $B_{op}$ , then the device output is pulled low; When the magnetic field strength is less than  $B_{rp}$ , then the device output is pulled high; When the magnetic field strength is between  $B_{op}$  and  $B_{rp}$ , then the device output remains in the previous state.

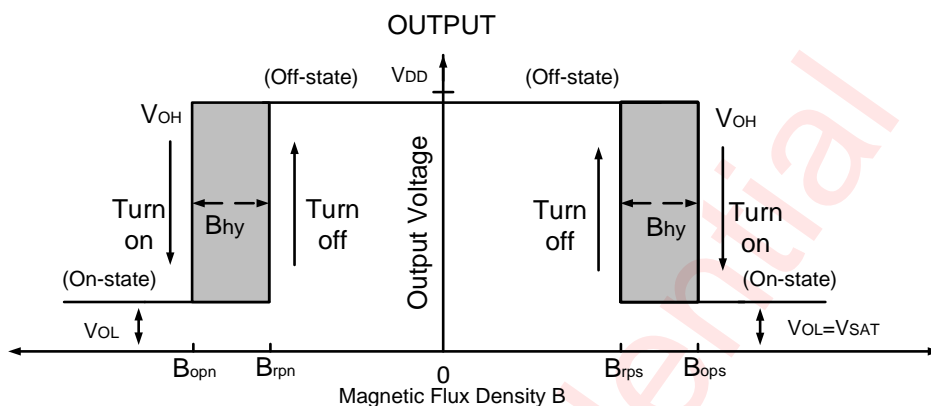


Figure 4 The Working Process of AW86504BSTR

## Absolute Maximum Ratings (NOTE1)

PARAMETERS	RANGE
Supply Voltage	6V
$V_{DD}$ Reverse Voltage $V_{DD}$	-0.3v
Supply Current	3mA
Output Voltage	-0.4V to $V_{DD}+0.4V$
Output Current	4mA
Operating Ambient Temperature $T_A$	-40°C to 85°C
Storage Temperature $T_{STG}$	-65°C to 150°C
Junction temperature $T_J$	-50°C to 165°C
Magnetic Flux	No limit
Lead temperature (soldering 10 seconds)	260°C
ESD Rating <sup>(NOTE2 3)</sup>	
Human Body Model (HMB) ESD capability	6kV
Charged-device model (CDM) ESD capability	1.5kV
Latch-up	
Test Condition: JESD78E	+ IT: 200mA - IT: 200mA

NOTE1: Conditions out of those ranges listed in "absolute maximum ratings" may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

NOTE2: The human body model test method: ESDA/JEDEC JS -001-2017.

NOTE3: Charge Device Model test method: ESDA/JEDEC JS-002-2018.

## Electrical Characteristics

Parameters Specification ( $V_{DD}=3.3V$ supply, $T_A=-40^{\circ}C$ to $85^{\circ}C$ except where otherwise specified.)						
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{DD}$	Supply Voltage	Operating, $T_J < 165^{\circ}C$	1.6		5.5	V
$I_{DD}(\text{awake})$	Supply Current	During awake period, $T_A = 25^{\circ}C$ , $V_{DD}=3.3V$	-	0.95	1.3	mA
$I_{DD}(\text{sleep})$		During sleep period, $T_A = 25^{\circ}C$ , $V_{DD}=3.3V$	-	0.43	-	$\mu A$
$I_{DD}(\text{avg})$	Average supply current	$T_A = 25^{\circ}C$ , $V_{DD} = 1.8V$		0.8		$\mu A$
		$T_A = 25^{\circ}C$ , $V_{DD} = 3.3V$		1.13		$\mu A$
$V_{OL}$	Output low voltage(on)	$I_{OUT} = 1\text{ mA}$	-	0.1	0.2	V
$V_{OH}$	Output high voltage(off)	$I_{OUT} = -1\text{ mA}$	$V_{DD}-0.2$	$V_{DD}-0.1$	-	V
$T_{\text{awake}}$	Awake time	(note)	-	40	60	$\mu s$
$T_{\text{period}}$	Period	(note)	-	50	75	ms
D.C.	Duty cycle	-	-	0.08	-	%
$f_c$	Chopping Frequency		-	500	-	kHz
$I_{OFF}$	Output Leakage Current	$V_{OUT} = 5.5\text{ V}$ ; Switch state=off	-	-	0.1	$\mu A$

Note: Maximum and minimum parameters values over operating temperature range are not tested in production. They are guaranteed by design, characterization and process control. The magnetic field strength (Gauss) required to cause the switch to change state (operate and release) will be as specified in the magnetic characteristics. To test the switch against the specified magnetic characteristics, the switch must be placed in a uniform magnetic field.

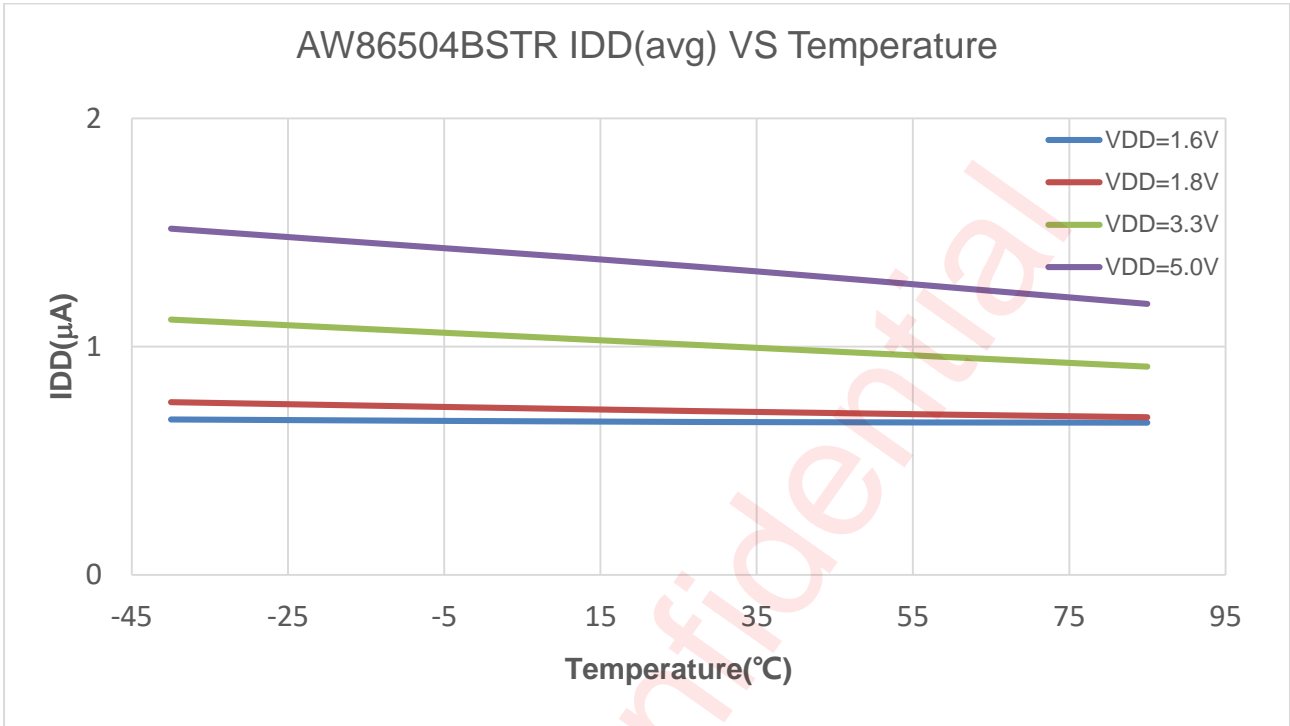
## Magnetic Characteristics

Magnetic Characteristics ( $T_A=+25, V_{DD}=3.3V$ , unless otherwise specified 1 mT=10 Gauss)						
Symbol	Characteristics	Test condition	Min	Typ	Max	Unit
Bops (south pole to part marking side)	Operation Point		20	30	40	Gauss
		$V_{DD}=1.6V$ to $5.5V$ , $T_A=-40$ to $+85$	18	30	42	
Bopn (north pole to part marking side)			-40	-30	-20	
		$V_{DD}=1.6V$ to $5.5V$ , $T_A=-40$ to $+85$	-42	-30	-18	
Brps (south pole to part marking side)	Release Point		10	20	30	
		$V_{DD}=1.6V$ to $5.5V$ , $T_A=-40$ to $+85$	8	20	32	
Brpn (north pole to part marking side)			-30	-20	-10	
		$V_{DD}=1.6V$ to $5.5V$ , $T_A=-40$ to $+85$	-32	-20	-8	
Bhy ( $ B_{opx}  -  B_{rpx} $ )	Hysteresis		-	10	-	

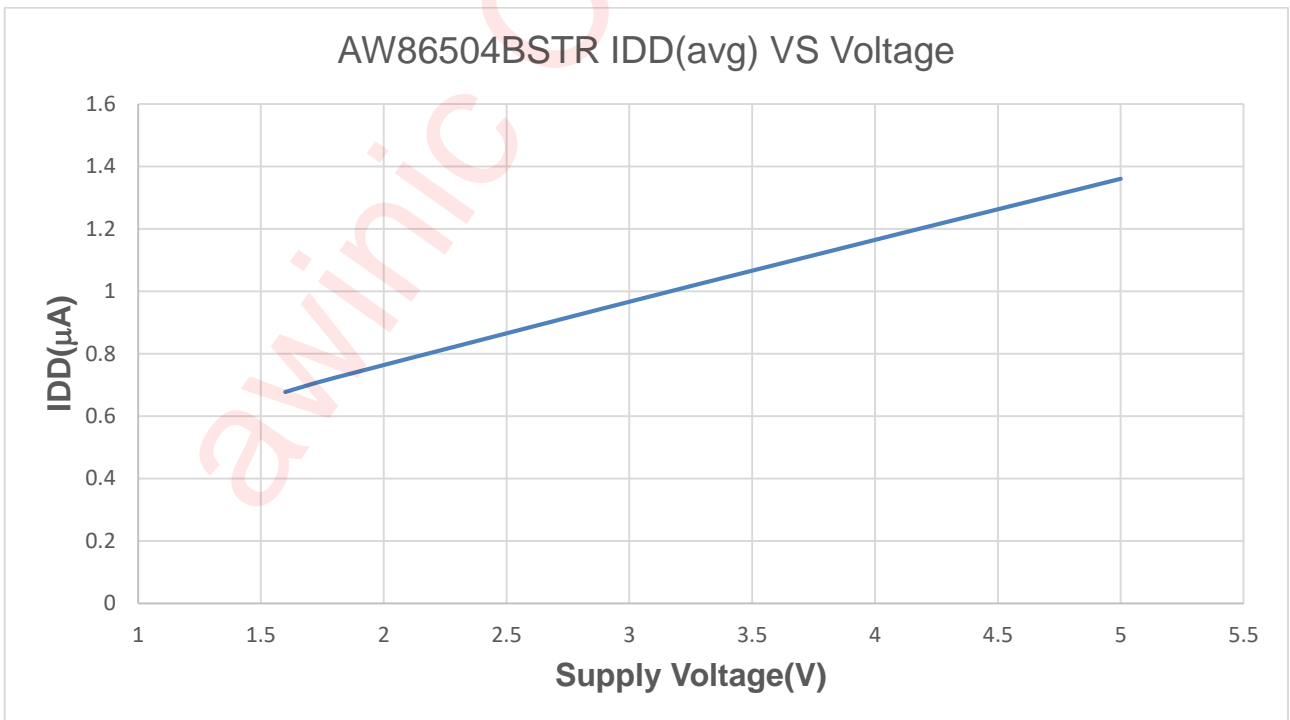
Notes: Typical data is at  $T_A=+25^\circ C$ ,  $V_{DD}=3.3V$ .

Maximum and minimum parameters values over operating temperature range are not tested in production. They are guaranteed by design, characterization and process control. The magnetic characteristics may vary with supply voltage, operating temperature and after soldering.

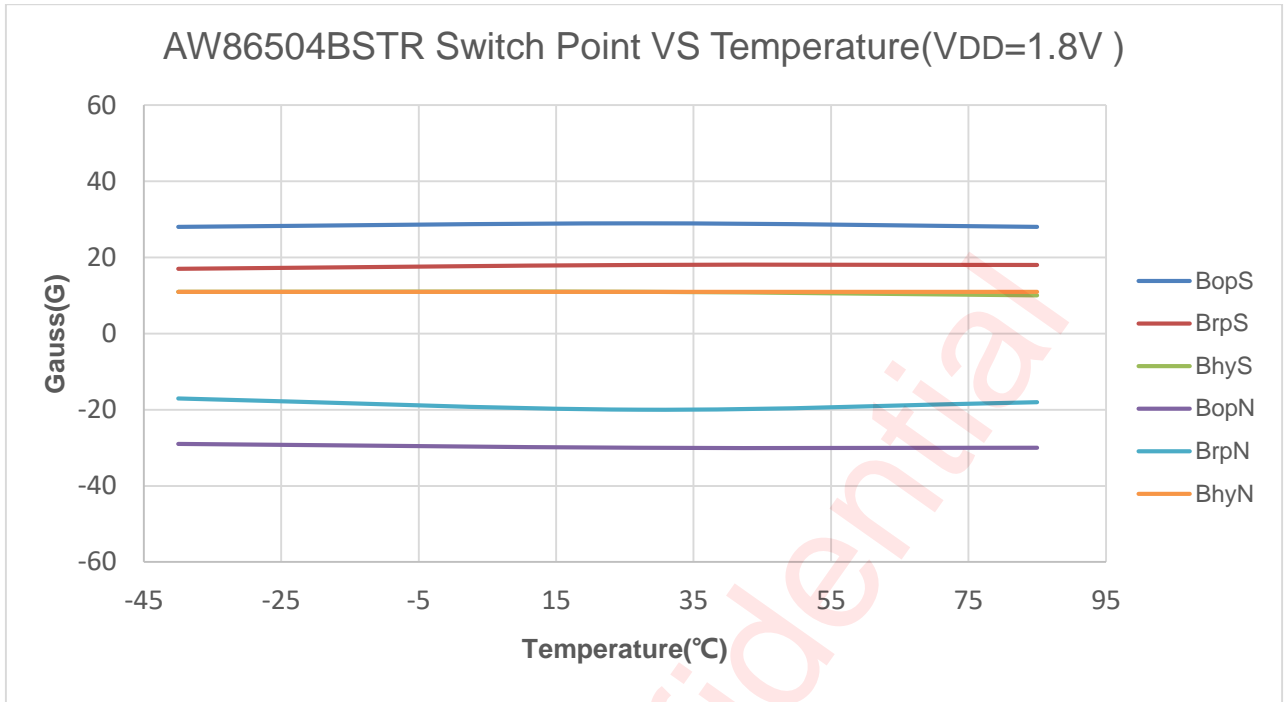
Typical Characteristics



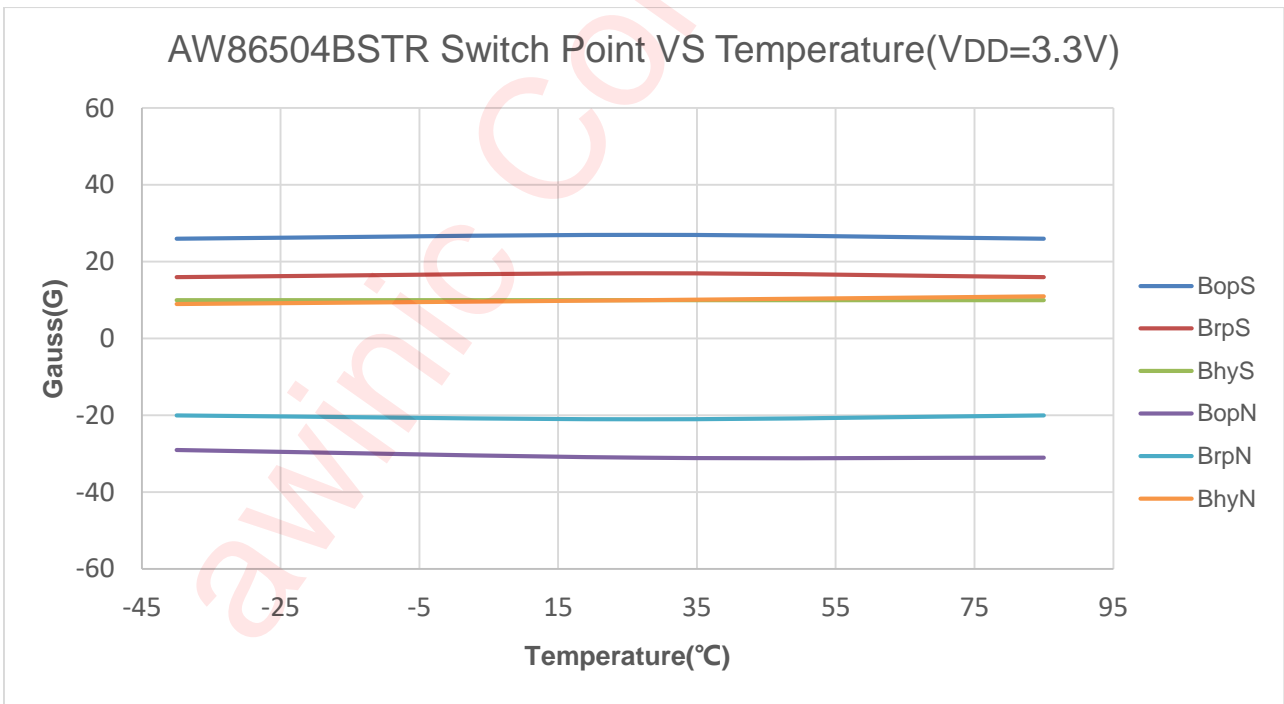
Ambient Temperature Ta[°C]  
IDD vs. Ta



Average Supply Current vs. Supply Voltage(Ta=27°C)



Ambient Temperature Ta[°C]  
Bop,Brp vs. Ta(V<sub>DD</sub>=1.8V)



Ambient Temperature Ta[°C]  
Bop,Brp vs. Ta(V<sub>DD</sub>=3.3V)

Figure 5 The Typical Characteristics of AW86504BSTR

## Application Information

It is recommended to connect an external capacitor of 0.1uF to VDD and GND. The noise of the injection device can be reduced.

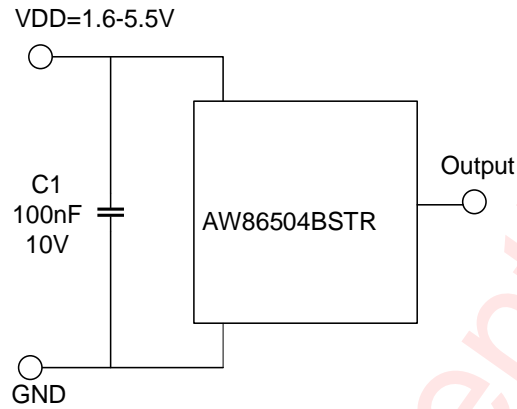
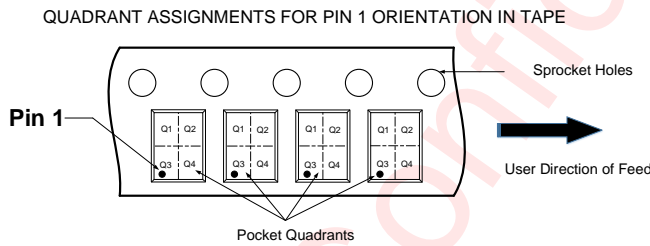
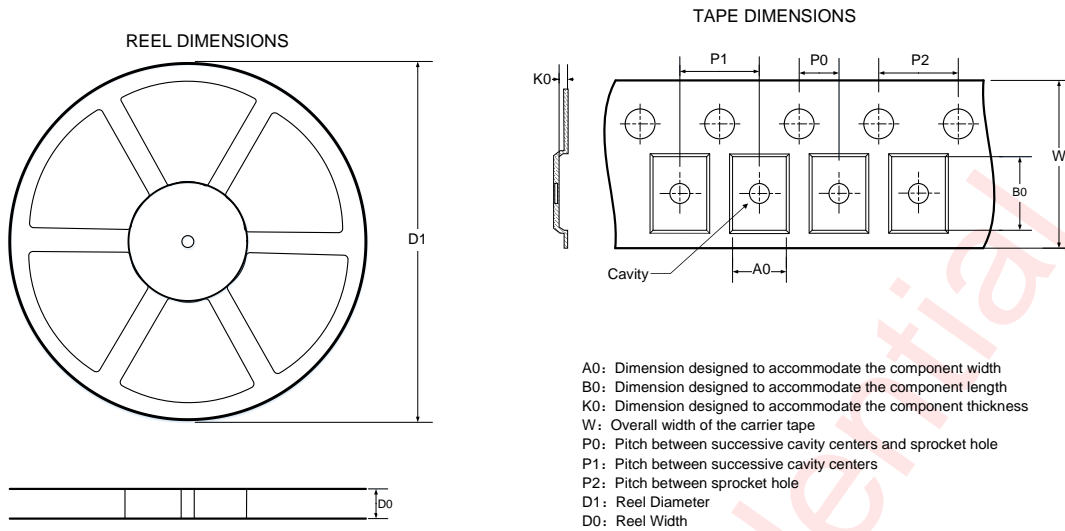


Figure 6 The Application Circuit of AW86504BSTR

## Tape And Reel Information



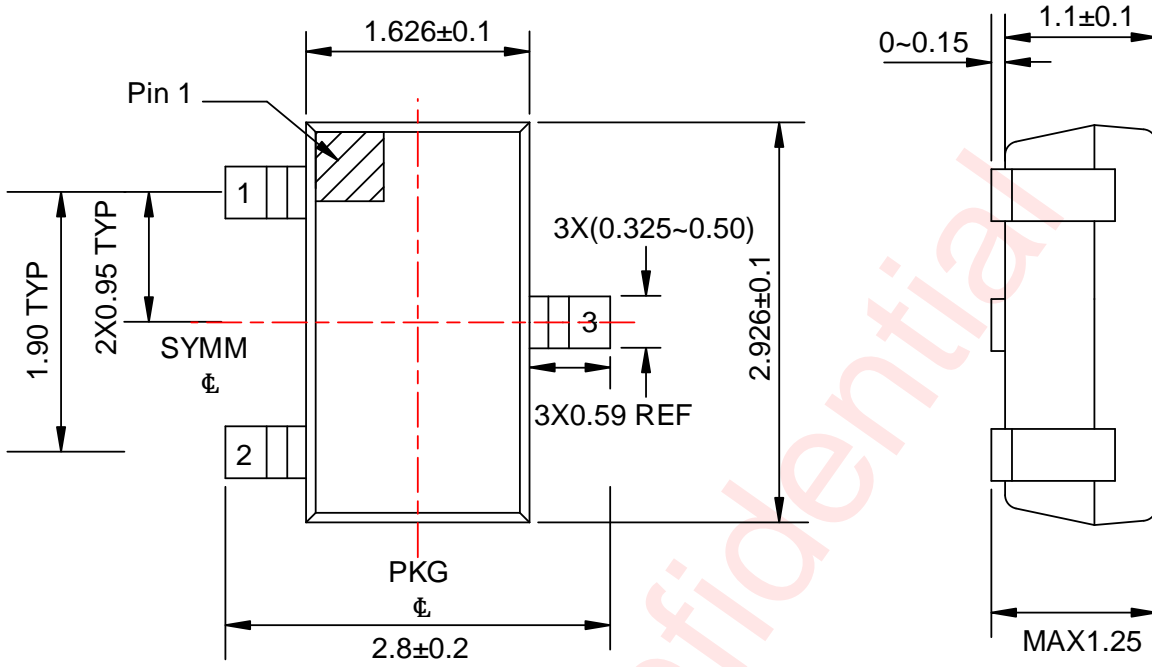
Note: The above picture is for reference only. Please refer to the value in the table below for the actual size

DIMENSIONS AND PIN1 ORIENTATION

D1 (mm)	D0 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
178	8.4	3.3	3.2	1.47	2	4	4	8	Q3

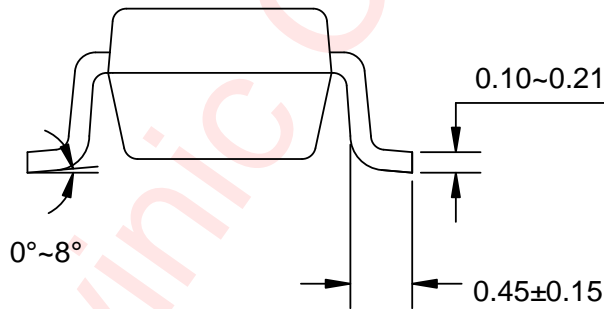
All dimensions are nominal

Package Description



Top View

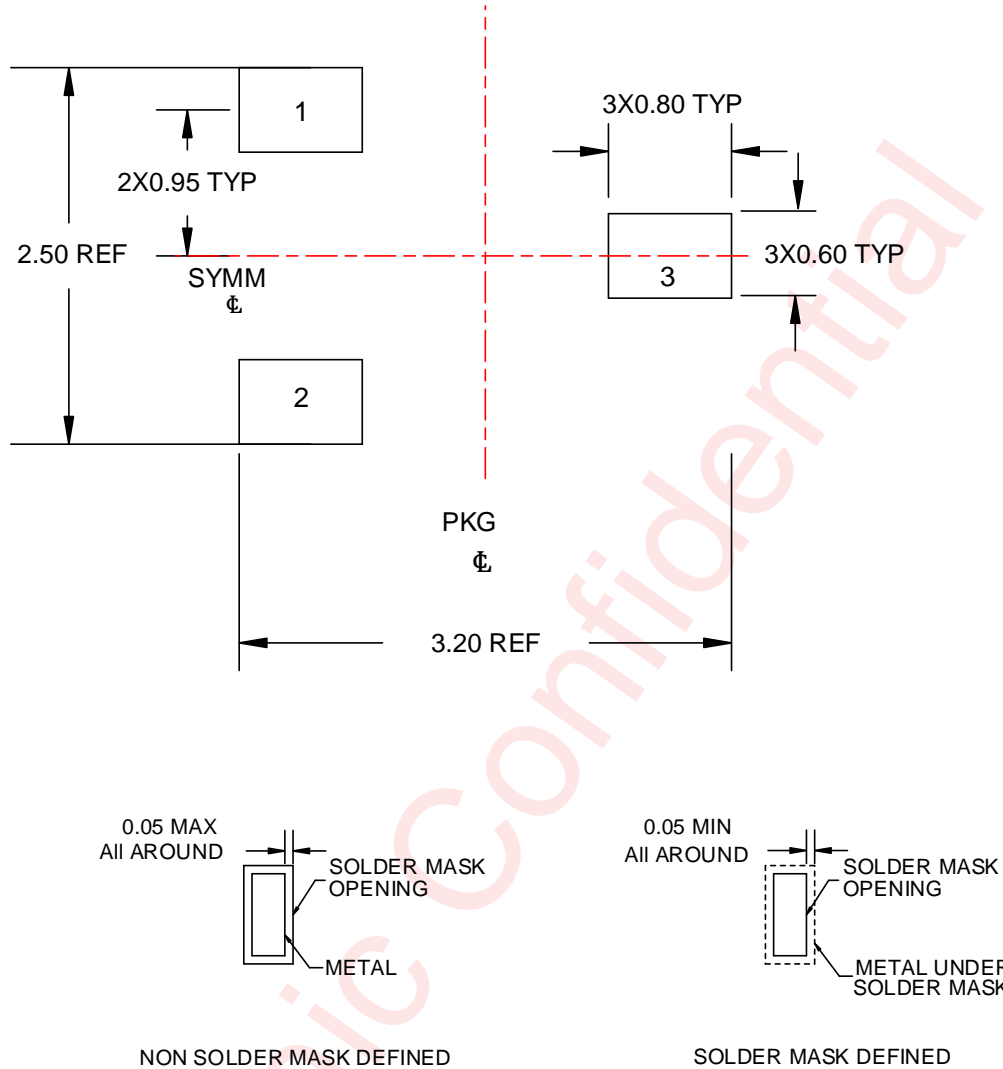
Side View



Side View

Unit: mm

Land Pattern Data



Unit: mm

## Revision History

Version	Date	Change Record
V1.0	Mar. 2022	Officially initial version

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